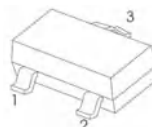


FEATURES

NPN General Purpose

SOT-23



1.BASE
2.EMITTER
3.COLLECTOR

1H

1GM

MMBTA05 Marking: 1H
MMBTA06 Marking: 1GM

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings 最大额定值

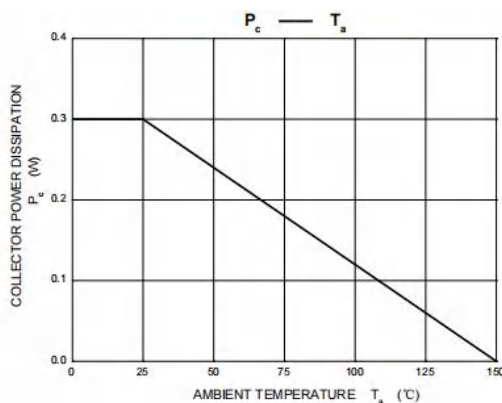
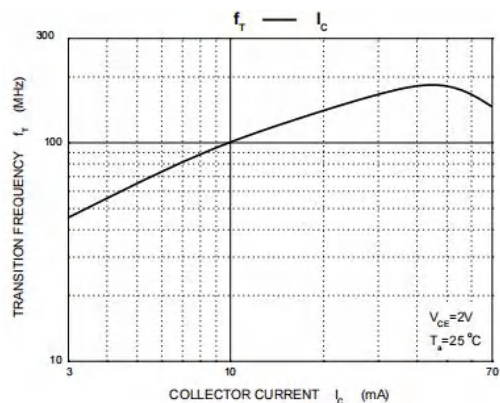
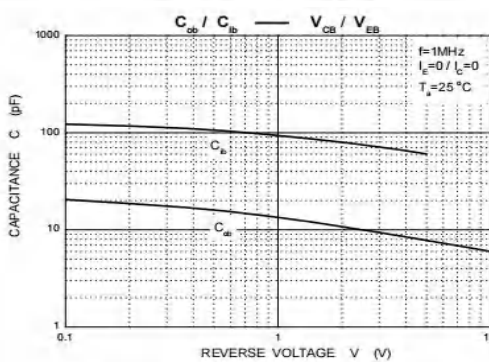
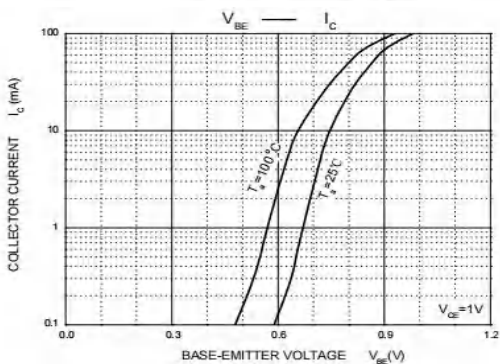
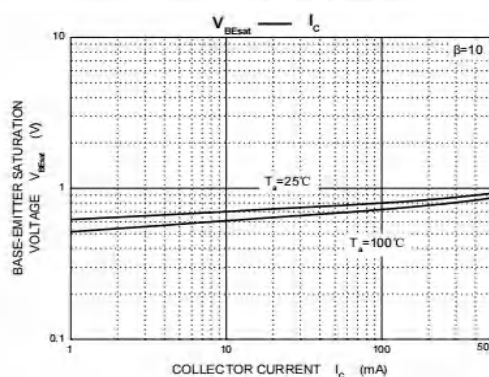
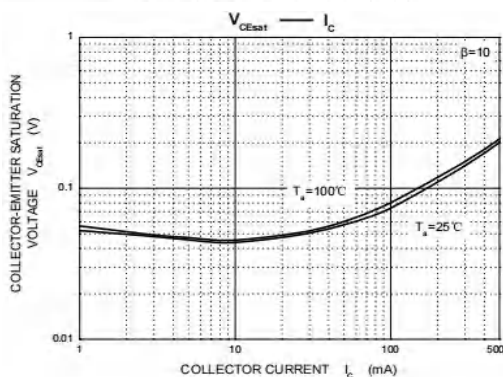
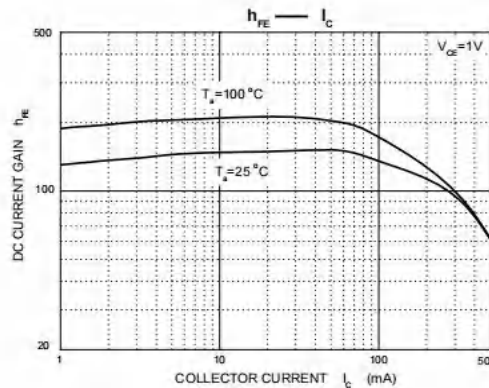
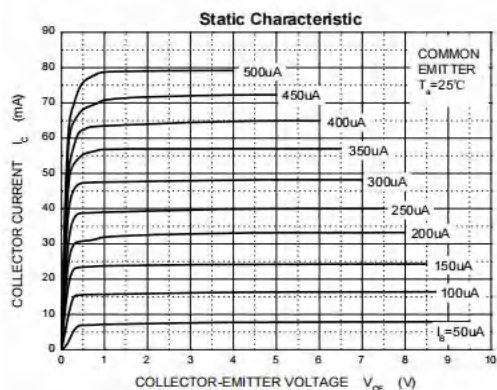
Characteristic 特性参数	Symbol 符号	Rat 额定值		Unit 单位
		MMBTA05	MMBTA06	
Collector-Base Voltage 集电极基极电压	V_{CBO}	60	80	V
Collector-Emitter Voltage 集电极发射极电压	V_{CEO}	60	80	V
Emitter-Base Voltage 发射极基极电压	V_{EBO}	4		V
Collector Current 集电极电流	I_C	500		mA
Power dissipation 耗散功率	$P_C(T_a=25^{\circ}\text{C})$	300		mW
Thermal Resistance Junction-Ambient 热阻	$R_{\theta JA}$	417		$^{\circ}\text{C}/\text{W}$
Junction and Storage Temperature 结温和储藏温度	T_J, T_{stg}	-55to+150 $^{\circ}\text{C}$		

Electrical Characteristics 电特性

($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

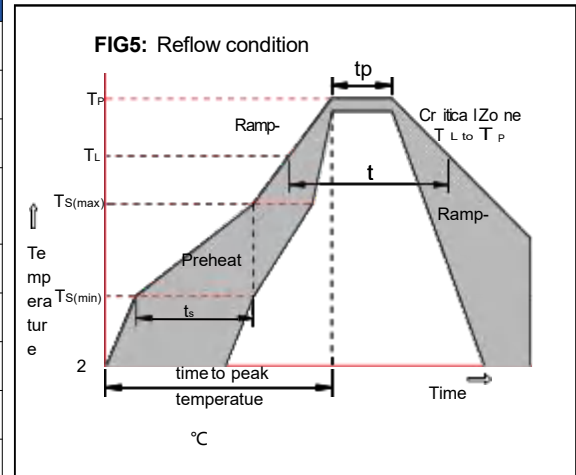
Characteristic 特性参数		Symbol 符号	Min 最小值	Type 典型值	Max 最大值	Unit 单位
Collector-Base Breakdown Voltage 集电极基极击穿电压 ($I_C=100\mu\text{A}$, $I_E=0$)	MMBTA05 MMBTA06	BV_{CBO}	60 80	—	—	V
Collector-Emitter Breakdown Voltage 集电极发射极击穿电压 ($I_C=10\text{mA}$, $I_B=0$)	MMBTA05 MMBTA06	BV_{CEO}	60 80	—	—	V
Emitter-Base Breakdown Voltage 发射极基极击穿电压 ($I_E=100\mu\text{A}$, $I_C=0$)		BV_{EBO}	4	—	—	V
Collector-Base Leakage Current 集电极基极漏电流	MMBTA05($V_{CB}=60\text{V}, I_E=0$) MMBTA06($V_{CB}=80\text{V}, I_E=0$)	I_{CBO}	—	—	100	nA
Collector-Emitter Leakage Current 集电极发射极漏电流	MMBTA05($V_{CB}=60\text{V}, I_B=0$) MMBTA06($V_{CB}=60\text{V}, I_B=0$)	I_{CEO}	—	—	100	nA
Emitter-Base Leakage Current 发射极基极漏电流($V_{EB}=4\text{V}$, $I_C=0$)		I_{EBO}	—	—	100	nA
DC Current Gain($V_{CE}=1\text{V}, I_C=10\text{mA}$) 直流电流增益($V_{CE}=1\text{V}, I_C=100\text{mA}$)		H_{FE}	100 100	—	400	
Collector-Emitter Saturation Voltage 集电极发射极饱和压降($I_C=100\text{mA}$, $I_B=10\text{mA}$)		$V_{CE(sat)}$	—	—	0.25	V
Base-Emitter Saturation Voltage 基极发射极饱和压降($I_C=100\text{mA}$, $I_B=10\text{mA}$)		$V_{BE(sat)}$	—	—	1.2	V
Base-Emitter On Voltage 基极发射极导通电压($V_{CE}=1\text{V}$, $I_C=100\text{mA}$)		$V_{BE(on)}$	—	—	1.2	V
Transition Frequency 特征频率($V_{CE}=2\text{V}$, $I_C=10\text{mA}$)		f_T	100	—	—	MHz
Output Capacitance 输出电容($V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$)		C_{ob}	—	10	—	pF

RATING AND CHARACTERISTIC CURVES



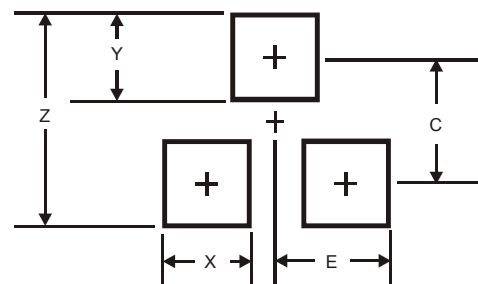
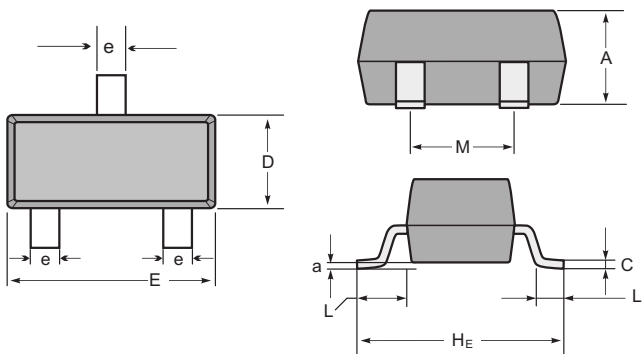
Soldering parameters

Reflow Condition		Pb-Free assembly (see as below)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_P)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_P)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C



Package Dimensions & Suggested Pad Layout

SOT23

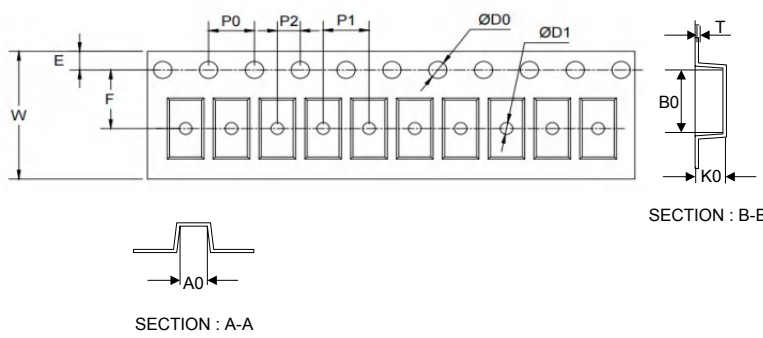
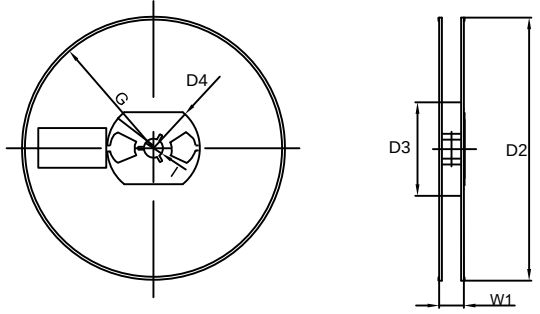


SOT-23 mechanical data

UNIT	A	C	D	E	H _E	e	M	L	L ₁	a
mm	max	1.1	0.15	1.4	3.0	2.6	0.5	1.95	0.55 (ref)	0.36 (ref)
	min	0.9	0.08	1.2	2.8	2.2	0.3	1.7		0.15
mil	max	43	6	55	118	102	20	77	22 (ref)	14 (ref)
	min	35	3	47	110	87	12	67		6

Dimensions	SOT23
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

Tape & reel specification

Tape		Symbol	Dimension (mm)
		P0	4.00±0.10
		P1	4.00±0.10
		P2	2.00±0.10
		D0	1.55±0.10
		D1	1.05±0.10
		E	1.55±0.10
		F	3.60±0.10
		W	8.00±0.10
		A0	3.80±0.20
		B0	3.25±0.20
		K0	1.45±0.10
		T	0.25±0.05
		D2	178.0±3.0
		D3	55Min.
		D4	R24.0±3.0
7" Reel		G	R82.0±3.0
		I	13.0±2.0
		W1	11.0±3.0
		Quantity: 3000PCS	